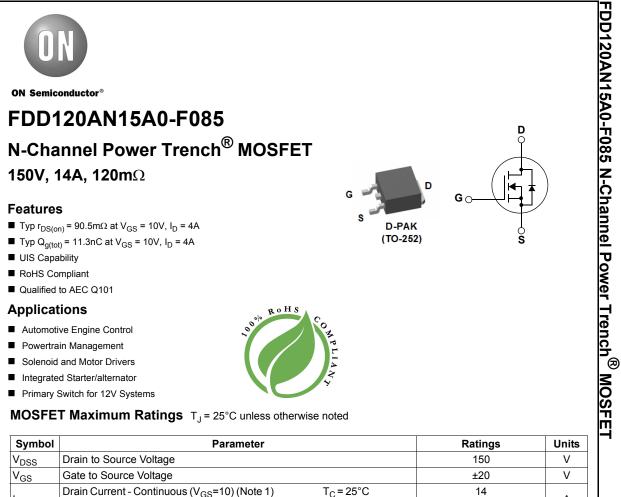
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Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C = 25°C	14	Α
Pulsed Drain Current	T _C = 25°C	See Figure4	~
Single Pulse Avalanche Energy	(Note 2)	122	mJ
Power Dissipation		65	W
Derate above 25°C		0.43	W/ºC
Operating and Storage Temperature		-55 to + 175	°C
Thermal Resistance Junction to Case		2.3	°C/W
Maximum Thermal Resistance Junction to Ambient	(Note 3)	52	°C/W
	Pulsed Drain Current Single Pulse Avalanche Energy Power Dissipation Derate above 25°C Operating and Storage Temperature Thermal Resistance Junction to Case	Pulsed Drain Current T _C = 25°C Single Pulse Avalanche Energy (Note 2) Power Dissipation Derate above 25°C Operating and Storage Temperature Thermal Resistance Junction to Case	Pulsed Drain Current $T_C = 25^{\circ}C$ See Figure4Single Pulse Avalanche Energy(Note 2)122Power Dissipation65Derate above $25^{\circ}C$ 0.43Operating and Storage Temperature-55 to + 175Thermal Resistance Junction to Case2.3

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD120AN15A0	FDD120AN15A0-F085	D-PAK(TO-252)	330mm	12mm	2500 units

Notes:

1: Current is limited by bondwire configuration.

2: Starting $T_J = 25^{\circ}C$, L = 27mH, $I_{AS} = 3A$, $V_{DD} = 100V$ during inductor charging and $V_{DD} = 0V$ during time in avalanche 3: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Symbol	Parameter	Test	Conditions	Min	Тур	Max	Units
Off Cha	racteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V	_{GS} = 0V	150	-	-	V
	Drain to Source Leakage Current	V _{DS} =150V,	T _J = 25 ^o C	-	-	1	μA
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V$	$T_{\rm J} = 175^{\rm o} {\rm C}({\rm Note}\;4)$	-	-	1	mA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D$ $I_D = 4A,$	T _J = 25 ^o C	2.0	3.0 90.5	4.0 120	V mΩ
	racteristics						
r _{DS(on)}	Drain to Source On Resistance					-	
D3(01)		V _{GS} = 10V	$T_{J} = 175^{\circ}C(Note 4)$	-	227	302	mΩ
Dynami _{Ciss}	C Characteristics			_	743	-	pF
C _{oss}	Output Capacitance	$V_{DS} = 25V, V$	_{GS} = 0V,	-	85	-	pF
C _{rss}	Reverse Transfer Capacitance	f = 1MHz		-	20	-	pF
Rg	Gate Resistance	f = 1MHz		-	3.4	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V	V _{GS} = 0 to 10	V V _{DD} = 75V	-	11.3	14	nC
Q _{g(th)}	Threshold Gate Charge	V_{GS} = 0 to 2V	' I _D = 4A	-	1.4	1.6	nC
Q _{gs}	Gate to Source Gate Charge			-	3.1	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	2.6	-	nC

Switching Characteristics

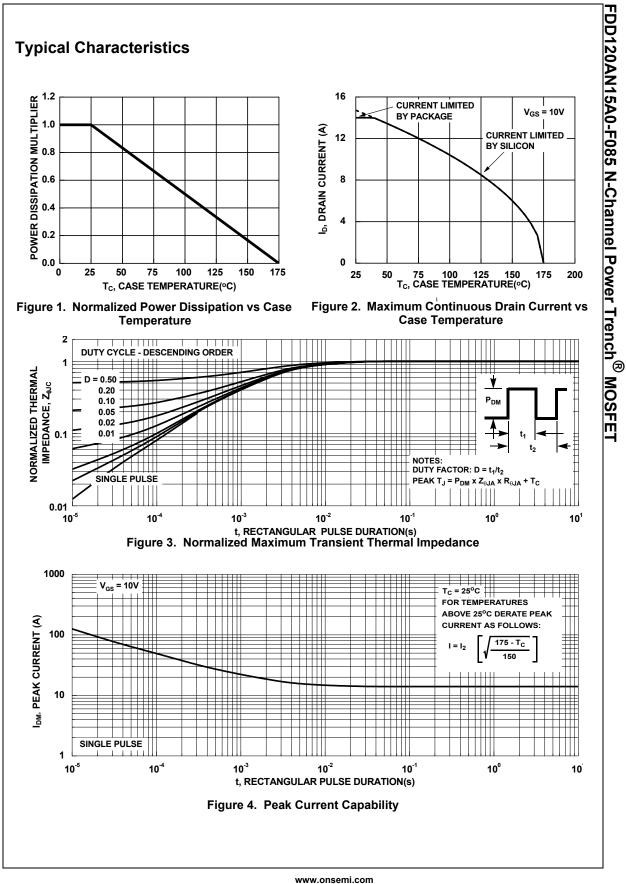
t _{on}	Turn-On Time		-	-	31	ns
t _{d(on)}	Turn-On Delay Time		-	14	-	ns
t _r	Rise Time	V _{DD} = 75V, I _D = 4A,	-	13	-	ns
t _{d(off)}	Turn-Off Delay Time	V_{DD} = 75V, I _D = 4A, V _{GS} = 10V, R _{GEN} = 24Ω	-	34	-	ns
t _f	Fall Time		-	15	-	ns
t _{off}	Turn-Off Time		-	-	59	ns

Drain-Source Diode Characteristics

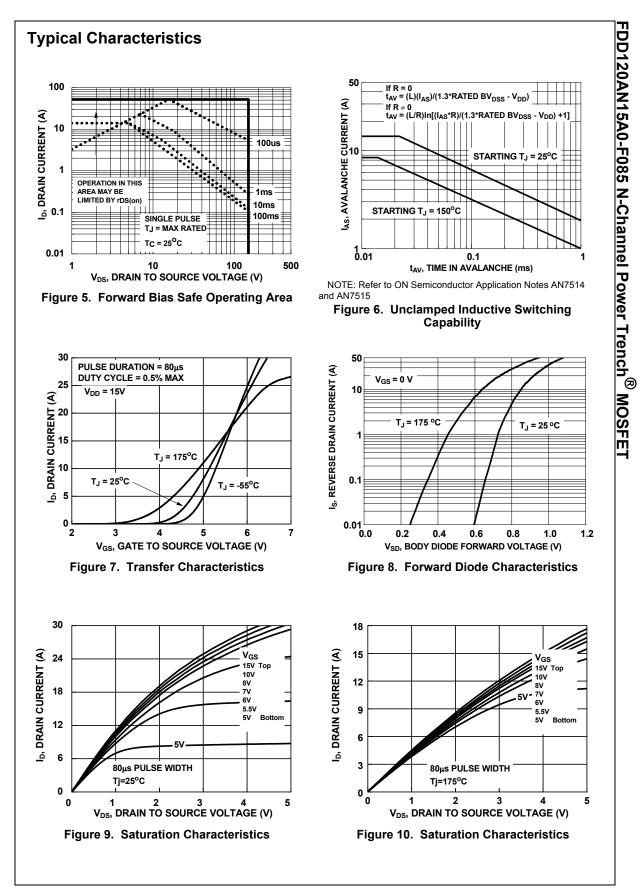
Vop Source to Urain Diode Voltade	Source to Drain Diode Voltage	I_{SD} = 4A, V_{GS} = 0V	-	-	1.25	V
	I _{SD} = 2A, V _{GS} = 0V	-	-	1.2	V	
T _{rr}	Reverse Recovery Time	I _F = 4A, dI _{SD} /dt = 100A/μs,	-	46	60	ns
Q _{rr}	Reverse Recovery Charge	V _{DD} =120V	-	94	108	nC

Notes:

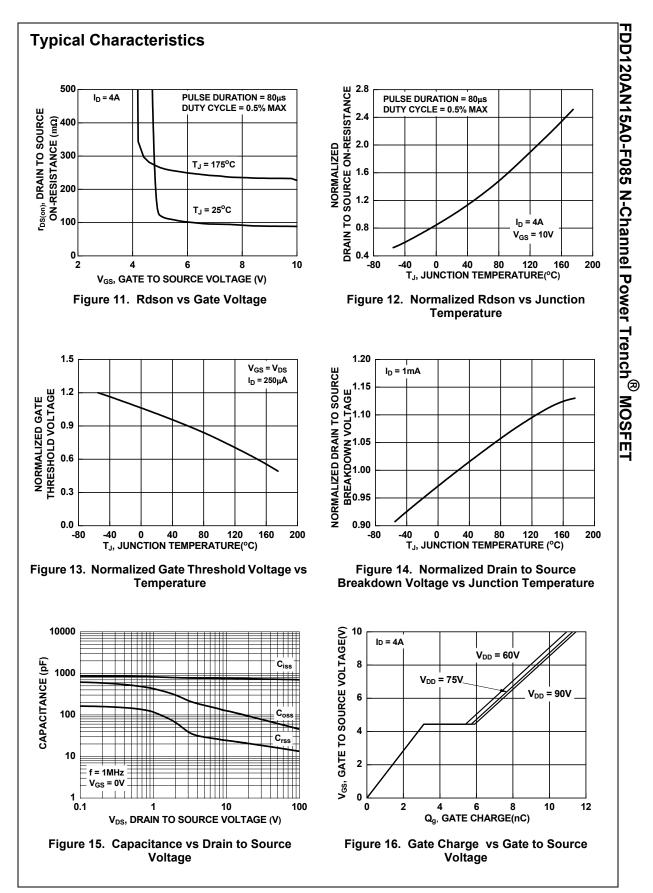
4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.



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